POWER FACTOR CONTROLLER

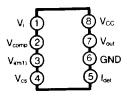
The KA7524B provides the necessary features to implement the Electronic BALLAST control and S.M.P.S application for designing on active power factor correction circuit.

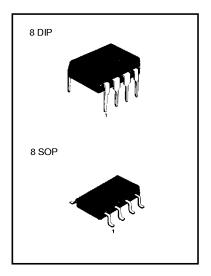
FEATURES

- Internal self-starting
- Micro power start up mode
- Included under voltage lockout circuit
- Internal 1% reference
- High output current : Peak 500mA

CONNECTION DIAGRAM

KA7524/KA7524D (8 DIP, 8 SOP)

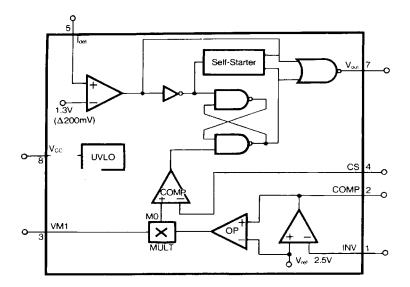




ORDERING INFORMATION

Device	Ref. Voltage	Package	Operating Temperature
KA7524B	1%	8 DIP	05 100%
KA7524BD	1%	8 SOP	-25 ~ + 100 ℃

BLOCK DIAGRAM





ABSOLUTE MAXIMUM RATINGS

Characteristic	Symbol	Value	Unit
Supply Voltage	V _{cc}	20	V
Peak driver output current	I _{O(P)}	500	m A
Detect clamping diode current	I _{DET}	10	m A
Output clamping diode current	I _{O(C.D)}	10	mA
Operating ambient temperature	T _{OPR}	-25 ~ + 100	$^{\circ}$
Storage Temperature T _{STG}		-65 ~ + 150	$^{\circ}$

ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Test Conditions	Min	Тур	Max	Unit	
Under Voltage Lockout Section							
Start Threshold Voltage	V _{TH(ST)}		9.2	10	10.8	V	
UV Lockout Hysteresis	V_{THS}		1.8	2.0	2.2	V	
Supply Current Section							
Start-Up Supply Current	ISTART	$V_{CC} < V_{TH}$		0.25	0.5	m A	
Operating Supply Current	lcc	V _{CC} = 12V, No Load		6	12	m A	
Dynamic Operating Current	Icc(D)	V _{CC} = 12V, f = 50KHz, C _{GS} = 1000PF		10	20	m A	
Reference Section(Note1)							
Reference Voltage	V_{REF}	KA7524B/BD	2.475	2.5	2.525	٧	
Line regulation	V_{REF}	12V < V _{CC} < 16V		0.1	10	mV	
Load Regulation	V_{REF}	0 < I _{REF} < 2mA		0.1	10	mV	
Temperature Stability	ST _T			20		mV	
Error Amplifier Section							
Input Offset Voltage	V _{IO}		-15		15	mV	
Input Bias Current	IBIAS		-1	-0.1	1	u A	
Large Signal Open Loop Gain	Gγ		60	100		dB	
Power Supply Rejection Ratio	PSRR		60	86		dB	
Output Current	Isource		2			m A	
Output Gurrent	I _{SINK}				-2	m A	
Output Voltage Range	$V_{O(P)}$		1.2		4	٧	
Unity Gain Bandwidth	UBW			1.0		MHz	
Phase Margin	MPH			57		\mathbb{C}	



ELCTRICAL CHARACTERISTICS(Continude)

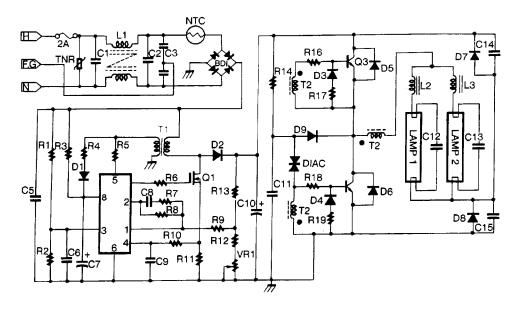
Characteristic	Symbol	Test Conditions	Min	Тур	Max	Unit
Multiplier Section						
M1 Input Voltage Range	V _{I(M1)}		0		2	٧
M2 Input Voltage Range	V _{I(M2)}		V _{REF}		V _{REF+1}	٧
Input Bias Current	I _{BIAS}		-2	-0.5	2	uA
Mulitiplier Gain (Note2)	G∨	$V_{I(M1)} = 0.5V, V_{I(M2)} = 3V$		8.0		u A
Multiplier Gain Stability	ST⊤			-0.2		%/°C
Current Sdnse Section						
Input Offset Voltage	V _{IO}		-10		10	mV
Input Bias Current	I _{BIAS}	0V < V _{CS} < 1.7V	-5		5	uA
C. Sense Delay to Output	t _{D(S)}	Error Amp Output = 3.7V		200	500	nS
Current Detect Section						
Input Voltage Threshold	V _{TH}		1.0	1.3	1.6	٧
Hysteresis	V _{THS}			200		mV
Input Low Clamp Voltage	V _{IC(L)}	I _{DET} = 0mA			0.95	٧
Input High Clamp Voltage	V _{IC(H)}	I _{DET} = 3mA	6.1	7.1		٧
Input Current	lı	0.9 < V _{DET} < 6V		5		u A
Input Clam Diode Current	Icp	V _{DET} < 0.9V, V _{DET} > 6V			3	m A
Current Detect Section	•	•				
Output Voltage(High)	V _{O(H)}	I _O = -10mA, V _{CC} = 12V	7	9		٧
Output Voltage(Low)	V _{O(L)}	I _O = 10mA, V _{CC} = 12V		0.8	1.8	٧
Rising Time	t _R	CL = 1000pF		100	200	nS
Falling Time	t _F	CL = 1000pF		90	200	nS
Self-Starting Section						
Self-Starting Time	tss		12			uS

Note 1. Reference can not be tested on the PKG



^{2.} $G_V = V_{O(M)} / (V_{I(M1)} * V_{I(M2)} - V_{REF})$

KA7524B/BD APPLICATION CIRCUIT



PART LIST

	Resistor		Capacitor		Semiconductor
R1	1.8M	C1	0.1uF	IC1	KA7524B
R2	10K	C2	0.1uF	Q1	IRF830
R3	100K	C3	4700pF	Q2	KSC5039
R4	3.3ohm	C4	4700pF	Q3	KSC5039
R5	22K	C5	0.1uF	D1	1N4004
R6	27ohm	C6	0.01uF	D2	1N4937
R7	2.2K	C7	100uF	D3	1N4148
R8	2.2M	C8	0.1uF	D4	1N4148
R9	150K	C9	3300pF	D5	FR107
R10	330ohm	C10	47uF/450V	D6	FR107
R11	0.75ohm	C11	0.1uF	D7	FR107
R12	5.1K	C12	3300pF	D8	FR107
R13	1M	C13	3300pF	BD1	PBP204
R14	390K	C14	0.01uF	TNR	12G471
R15	3.9M	C15	0.01uF	DIAIC	32V
R16	5.1ohm				
R17	27ohm	Magnetics			
R18	5.1ohm	T1	El-25 (PC30): P = 70T		= 0.5mm
R19	27ohm	T2 L1	D15 (GP-5): P = 3T, S		
VR1	5K	L1 L2, L3	EE-25 (Iron Power) 80 EI-25 (PC30): 150T, G		
NTC	10ohm		2.25 (1.550). 1501, 6	щр = 0. 1 111111	



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